

CMOS Digital Integrated Circuits Silicon Monolithic

74VHCT9541AFT

1. Functional Description

· Octal Universal Schmitt Buffer with 3-State Outputs

2. General

The~74VHCT9541AFT~is~an~ultra-high-speed~octal~Schmitt~buffer~fabricated~using~silicon-gate~CMOS~technology.

The 74VHCT9541AFT combines low power consumption of CMOS with Schottky TTL speeds.

The input voltage are compatible with TTL output voltage.

This device may be used as a level converter for interfacing 3.3 V to 5 V system.

The outputs can be put in the high-impedance state by placing a logic HIGH on the Enable (G) input. The CONT input determines the logical inversion of data. A logic LOW on the CONT input configures the 74VHCT9541AFT as an inverter; a logic HIGH on the CONT input configures the 74VHCT9541AFT as a buffer.

All the inputs have hysteresis between the positive-going and negative-going thresholds. Thus the 74VHCT9541AFT is capable of squaring up transitions of slowly changing input signals and provides an improved noise immunity.

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (Note) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, etc.

Note: Output in off-state

3. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range: $T_{opr} = -40$ to 125 °C
- (3) High speed: $t_{pd} = 6.5 \text{ ns (typ.)}$ at $V_{CC} = 5.0 \text{ V}$
- (4) Low power dissipation: $I_{CC} = 4.0 \mu A \text{ (max)} \text{ (}T_a = 25 \text{ °C)}$
- (5) Compatible with TTL inputs: $V_{IL} = 0.5 \text{ V (max)}$

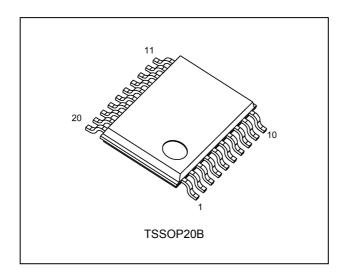
$$V_{IH} = 2.1 \text{ V (min)}$$

- (6) Power down protection is provided on all inputs.
- (7) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$
- (8) Input terminals are at the opposite side of Output terminals

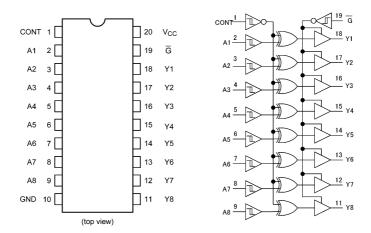
Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.



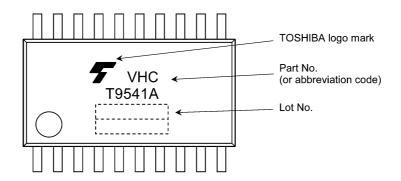
4. Packaging



5. Pin Assignment



6. Marking



7. Truth Table

| Input G | Input CONT | Input An | Output Yn |
|---------|------------|----------|-----------|
| Н | X | X | Z |
| L | L | L | Н |
| L | L | Н | L |
| L | Н | L | L |
| L | Н | Н | Н |

- X: Don't care
- Z: High impedance

Rev.2.0



8. Absolute Maximum Ratings (Note)

| Characteristics | Symbol | Note | Rating | Unit |
|---------------------------------|------------------|----------|-------------------------------|------|
| Supply voltage | V _{CC} | | -0.5 to 7.0 | V |
| Input voltage | V _{IN} | | -0.5 to 7.0 | V |
| Output voltage | V _{OUT} | (Note 1) | -0.5 to 7.0 | V |
| | | (Note 2) | -0.5 to V _{CC} + 0.5 | |
| Input diode current | I _{IK} | | -20 | mA |
| Output diode current | I _{OK} | (Note 3) | ±20 | mA |
| Output current | I _{OUT} | | ±25 | mA |
| V _{CC} /ground current | I _{CC} | | ±75 | mA |
| Power dissipation | P _D | (Note 4) | 180 | mW |
| Storage temperature | T _{stg} | | -65 to 150 | °C |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: Output in OFF state.
- Note 2: High (H) or Low (L) state. IOUT absolute maximum rating must be observed.
- Note 3: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$
- Note 4: 180 mW in the range of T_a = -40 to 85 °C. From T_a = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

9. Operating Ranges (Note)

| Characteristics | Symbol | Note | Rating | Unit |
|-----------------------|------------------|----------|----------------------|------|
| Supply voltage | V _{CC} | | 4.0 to 5.5 | V |
| Input voltage | V _{IN} | | 0 to 5.5 | V |
| Output voltage | V _{OUT} | (Note 1) | 0 to 5.5 | V |
| | | (Note 2) | 0 to V _{CC} | |
| Operating temperature | T _{opr} | | -40 to 125 | °C |

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either V_{CC} or GND.

Note 1: Output in OFF state.

Note 2: High (H) or Low (L) state.



10. Electrical Characteristics

10.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

| Characteristics | Symbol | Test Condition | | V _{CC} (V) | Min | Тур. | Max | Unit |
|--|------------------|---|--|---------------------|------|------|-------|------|
| Positive threshold voltage | V _P | _ | | 4.5 | _ | _ | 1.90 | V |
| | | | | 5.5 | _ | _ | 2.10 | |
| Negative threshold voltage | V _N | _ | | 4.5 | 0.50 | _ | _ | V |
| | | | | 5.5 | 0.60 | _ | _ | |
| Hysteresis voltage | V _H | _ | | 4.5 | 0.40 | _ | 1.40 | V |
| | | | | 5.5 | 0.40 | _ | 1.50 | |
| High-level output voltage | V _{OH} | V _{IN} = V _{IH} or V _{IL} | I _{OH} = -50 μA | 4.5 | 4.4 | 4.5 | _ | V |
| | | | I_{OH} = -8 mA | 4.5 | 3.94 | _ | _ | |
| Low-level output voltage | V _{OL} | V _{IN} = V _{IH} or V _{IL} | I _{OL} = 50 μA | 4.5 | _ | 0.0 | 0.1 | V |
| | | | I _{OL} = 8 mA | 4.5 | _ | _ | 0.36 | |
| 3-state output OFF-state leakage current | I _{OZ} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$ | · | 5.5 | _ | _ | ±0.25 | μА |
| Input leakage current | I _{IN} | V _{IN} = 5.5 V or GND | | 0 to 5.5 | _ | _ | ±0.1 | μА |
| Quiescent supply current | Icc | V _{IN} = V _{CC} or GND | V _{IN} = V _{CC} or GND | | _ | _ | 4.0 | μА |
| | I _{CCT} | Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND | | 5.5 | _ | _ | 1.35 | mA |
| Output leakage current (Power-OFF) | I _{OPD} | V _{OUT} = 5.5 V | | 0 | _ | _ | 0.5 | μА |

10.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

| Characteristics | Symbol | Test Condition | | V _{CC} (V) | Min | Max | Unit |
|--|------------------|---|--------------------------|---------------------|------|------|------|
| Positive threshold voltage | V _P | _ | | 4.5 | _ | 1.90 | V |
| | | | | 5.5 | _ | 2.10 | |
| Negative threshold voltage | V _N | _ | | 4.5 | 0.50 | _ | V |
| | | | | 5.5 | 0.60 | _ | |
| Hysteresis voltage | V _H | _ | | 4.5 | 0.40 | 1.40 | V |
| | | | | 5.5 | 0.40 | 1.50 | |
| High-level output voltage | V _{OH} | V _{IN} = V _{IH} or V _{IL} | I _{OH} = -50 μA | 4.5 | 4.4 | _ | V |
| | | | I _{OH} = -8 mA | 4.5 | 3.80 | _ | |
| Low-level output voltage | V _{OL} | V _{IN} = V _{IH} or V _{IL} | I _{OL} = 50 μA | 4.5 | _ | 0.1 | V |
| | | | I _{OL} = 8 mA | 4.5 | _ | 0.44 |] |
| 3-state output OFF-state leakage current | I _{OZ} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$ | | 5.5 | _ | ±2.5 | μА |
| Input leakage current | I _{IN} | V _{IN} = 5.5 V or GND | | 0 to 5.5 | _ | ±1.0 | μА |
| Quiescent supply current | I _{CC} | V _{IN} = V _{CC} or GND | | 5.5 | _ | 40.0 | μА |
| | I _{CCT} | Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND | | 5.5 | | 1.50 | mA |
| Output leakage current (Power-OFF) | I _{OPD} | V _{OUT} = 5.5 V | | 0 | | 5.0 | μА |



10.3. DC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C)

| Characteristics | Symbol | Test Condition | ı | V _{CC} (V) | Min | Max | Unit |
|--|------------------|---|--|---------------------|------|-------|------|
| Positive threshold voltage | V _P | _ | | 4.5 | _ | 1.90 | V |
| | | | | 5.5 | _ | 2.10 | |
| Negative threshold voltage | V _N | _ | | 4.5 | 0.50 | _ | V |
| | | | | 5.5 | 0.60 | _ |] |
| Hysteresis voltage | V _H | _ | | 4.5 | 0.40 | 1.40 | V |
| | | | | 5.5 | 0.40 | 1.50 |] |
| High-level output voltage | V _{OH} | V _{IN} = V _{IH} or V _{IL} | I _{OH} = -50 μA | 4.5 | 4.4 | _ | V |
| | | | I _{OH} = -8 mA | 4.5 | 3.70 | _ | |
| Low-level output voltage | V _{OL} | V _{IN} = V _{IH} or V _{IL} | I _{OL} = 50 μA | 4.5 | _ | 0.1 | V |
| | | | I _{OL} = 8 mA | 4.5 | _ | 0.55 | |
| 3-state output OFF-state leakage current | I _{OZ} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$ | | 5.5 | _ | ±10.0 | μА |
| Input leakage current | I _{IN} | V _{IN} = 5.5 V or GND | | 0 to 5.5 | _ | ±2.0 | μА |
| Quiescent supply current | Icc | V _{IN} = V _{CC} or GND | V _{IN} = V _{CC} or GND | | _ | 80.0 | μА |
| Quiescent supply current | I _{CCT} | Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND | | 5.5 | _ | 1.50 | mA |
| Output leakage current (Power-OFF) | I _{OPD} | V _{OUT} = 5.5 V | | 0 | _ | 20.0 | μА |

10.4. AC Characteristics (Unless otherwise specified, T_a = 25 °C, Input: t_r = t_f = 3 ns)

| Characteristics | Symbol | Note | Test Condition | V _{CC} (V) | C _L (pF) | Min | Тур. | Max | Unit |
|-------------------------------|--------------------------------------|----------|-------------------------|---------------------|---------------------|-----|------|------|------|
| Propagation delay time | t _{PLH} ,t _{PHL} | | _ | 5.0 ± 0.5 | 15 | _ | 6.5 | 8.5 | ns |
| (An - Yn) | | | | | 50 | _ | 8.6 | 11.5 | |
| Propagation delay time | t _{PLH} ,t _{PHL} | | _ | 5.0 ± 0.5 | 15 | _ | 8.2 | 10.5 | ns |
| (CONT - Yn) | | | | | 50 | _ | 10.8 | 14.5 | |
| 3-state output enable time | t _{PZL} ,t _{PZH} | | $R_L = 1 k\Omega$ | 5.0 ± 0.5 | 15 | _ | 6.9 | 8.5 | ns |
| | | | | | 50 | _ | 9.1 | 12.5 | |
| 3-state output disable time | t_{PLZ}, t_{PHZ} | | $R_L = 1 k\Omega$ | 5.0 ± 0.5 | 50 | _ | 7.4 | 11.5 | ns |
| Output skew | t _{osLH} ,t _{osHL} | (Note 1) | _ | 5.0 ± 0.5 | 50 | _ | _ | 1.0 | ns |
| Input capacitance | C _{IN} | | | _ | | _ | 4 | 10 | pF |
| Output capacitance | C _{OUT} | | | _ | | _ | 9 | _ | pF |
| Power dissipation capacitance | C _{PD} | (Note 2) | f _{IN} = 1 MHz | | | _ | 16 | _ | pF |

Note 1: Parameter guaranteed by design. $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$ (per bit)



10.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

| Characteristics | Symbol | Note | Test Condition | V _{CC} (V) | C _L (pF) | Min | Max | Unit |
|-----------------------------|--------------------------------------|----------|-------------------|---------------------|---------------------|-----|------|------|
| Propagation delay time | t _{PLH} ,t _{PHL} | | _ | 5.0 ± 0.5 | 15 | 1.0 | 10.0 | ns |
| (An - Yn) | | | | | 50 | 1.0 | 13.0 | |
| Propagation delay time | t _{PLH} ,t _{PHL} | | _ | 5.0 ± 0.5 | 15 | 1.0 | 12.0 | ns |
| (CONT - Yn) | | | | | 50 | 1.0 | 17.0 | |
| 3-state output enable time | t_{PZL}, t_{PZH} | | $R_L = 1 k\Omega$ | 5.0 ± 0.5 | 15 | 1.0 | 10.0 | ns |
| | | | | | 50 | 1.0 | 14.5 | |
| 3-state output disable time | t_{PLZ}, t_{PHZ} | | $R_L = 1 k\Omega$ | 5.0 ± 0.5 | 50 | 1.0 | 13.0 | ns |
| Output skew | t _{osLH} ,t _{osHL} | (Note 1) | _ | 5.0 ± 0.5 | 50 | _ | 1.0 | ns |
| Input capacitance | C _{IN} | · | | _ | | _ | 10 | pF |

Note 1: Parameter guaranteed by design. $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$

10.6. AC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C, Input: t_r = t_f = 3 ns)

| Characteristics | Symbol | Note | Test Condition | V _{CC} (V) | C _L (pF) | Min | Max | Unit |
|-----------------------------|--------------------------------------|----------|-------------------|---------------------|---------------------|-----|------|------|
| Propagation delay time | t _{PLH} ,t _{PHL} | | _ | 5.0 ± 0.5 | 15 | 1.0 | 11.0 | ns |
| (An - Yn) | | | | | 50 | 1.0 | 14.0 | |
| Propagation delay time | t _{PLH} ,t _{PHL} | | _ | 5.0 ± 0.5 | 15 | 1.0 | 13.0 | ns |
| (CONT - Yn) | | | | | 50 | 1.0 | 19.0 | |
| 3-state output enable time | t _{PZL} ,t _{PZH} | | $R_L = 1 k\Omega$ | 5.0 ± 0.5 | 15 | 1.0 | 11.0 | ns |
| | | | | | 50 | 1.0 | 16.0 | |
| 3-state output disable time | t_{PLZ}, t_{PHZ} | | $R_L = 1 k\Omega$ | 5.0 ± 0.5 | 50 | 1.0 | 14.0 | ns |
| Output skew | t _{osLH} ,t _{osHL} | (Note 1) | _ | 5.0 ± 0.5 | 50 | _ | 1.0 | ns |
| Input capacitance | C _{IN} | | _ | | | _ | 10 | pF |

Note 1: Parameter guaranteed by design. $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$

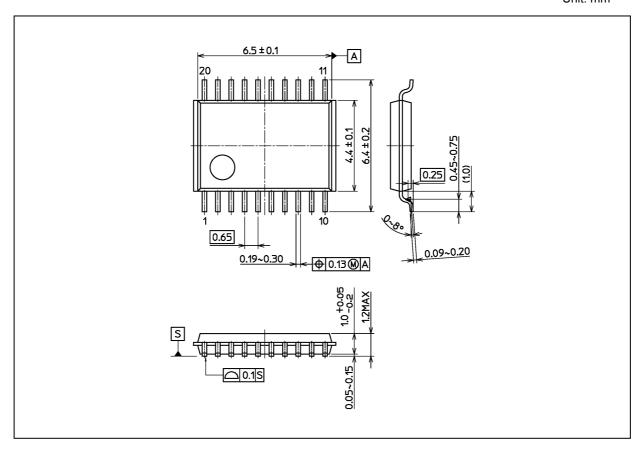
11. Noise Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_f = t_f = 3$ ns)

| Characteristics | Symbol | Test Condition | V _{CC} (V) | Тур. | Limit | Unit |
|--|------------------|------------------------|---------------------|------|-------|------|
| Quiet output maximum dynamic V _{OL} | V _{OLP} | C _L = 50 pF | 5.0 | 1.0 | 1.5 | V |
| Quiet output minimum dynamic V _{OL} | V _{OLV} | C _L = 50 pF | 5.0 | -0.3 | -1.5 | V |
| Minimum high-level dynamic input voltage | V _{IHD} | C _L = 50 pF | 5.0 | _ | 2.1 | V |
| Maximum low-level dynamic input voltage | V_{ILD} | C _L = 50 pF | 5.0 | | 0.5 | V |



Package Dimensions

Unit: mm



Weight: 0.071 g (typ.)

| | Package Name(s) |
|--------------------|-----------------|
| Nickname: TSSOP20B | |

Rev.2.0



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74LVC1G17FW4-7 74LVC1G126FZ4-7 BCM6302KMLG 74LVC1G07FZ4-7 74LVC1G125FW4-7